NPN Epitaxial Planar Silicon Transistor

15C01M



Low-Frequency General-Purpose Amplifier Applications

Applications

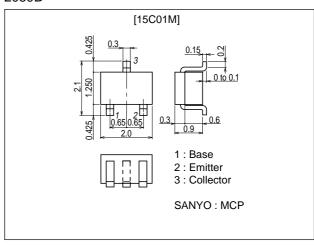
• Low-frequency Amplifier, muting circuit.

Features

- Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance). R_{CE} (sat) typ.=0.58Ω [I_C=0.7A, I_B=35mA].
- Ultrasmall package facilitates miniaturization in end products.
- Small ON-resistance (Ron).

Package Dimensions

unit : mm 2059B



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|--------|--|-------------|------|
| Collector-to-Base Voltage | VCBO | | 20 | V |
| Collector-to-Emitter Voltage | VCEO | | 15 | V |
| Emitter-to-Base Voltage | VEBO | | 5 | V |
| Collector Current | IC | | 700 | mA |
| Collector Current (Pulse) | ICP | | 1.4 | А |
| Collector Dissipation | PC | Mounted on a glass epoxy board (20×30×1.6mm) | 300 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|-----------------------|---|---------|-----|-------------|----------|
| | | | min | typ | max | Unit |
| Collector Cutoff Current | ІСВО | V _{CB} =15V, I _E =0 | | | 0.1 | μΑ |
| Emitter Cutoff Current | IEBO | VEB=4V, IC=0 | | | 0.1 | μA |
| DC Current Gain | hFE | V _{CE} =2V, I _C =10mA | 300 | | 800 | |
| Gain-Bandwidth Product | fT | V _{CE} =2V, I _C =50mA | | 330 | | MHz |
| Output Capacitance | Cob | V _{CB} =10V, f=1MHz | | 3.2 | | pF |
| Collector-to-Emitter Saturation Voltage | V _{CE} (sat) | IC=200mA, IB=10mA | | 150 | 300 | mV |
| Base-to-Emitter Saturation Voltage | V _{BE} (sat) | IC=200mA, IB=10mA | | 0.9 | 1.2 | V |
| Jarking · VP | | | | C | ontinued or | nevt neg |

Marking : YP

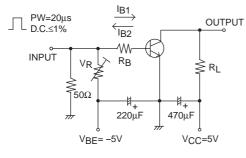
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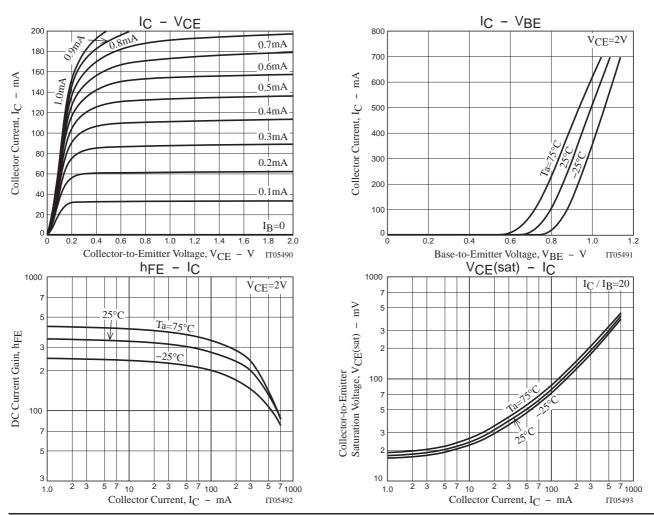
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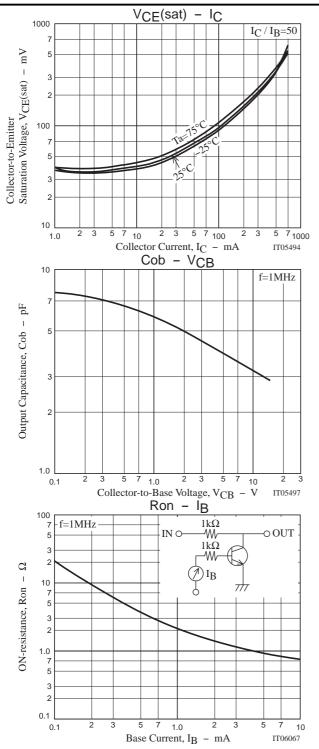
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------|-----------------------------|---------|-----|-----|------|
| | | | min | typ | max | Unit |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | IC=10μA, IE=0 | 20 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO | IC=1mA, R _{BE} =∞ | 15 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | IE=10μA, IC=0 | 5 | | | V |
| Turn-ON Time | ton | See specified Test Circuit. | | 30 | | ns |
| Storage Time | tstg | See specified Test Circuit. | | 77 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 40 | | ns |

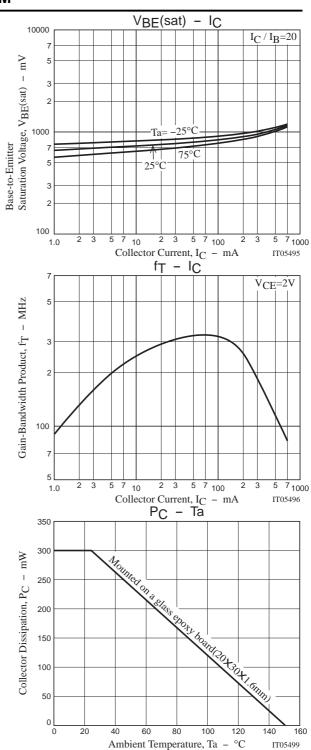
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=500mA$







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